

2521/105, 2602/106

2601/106, 2603/106

**ELECTRICAL MEASUREMENTS AND  
ANALOGUE ELECTRONICS I**

June/July 2017

Time: 3 hours



**THE KENYA NATIONAL EXAMINATIONS COUNCIL**

**DIPLOMA IN ELECTRICAL AND ELECTRONIC ENGINEERING  
(POWER OPTION)  
(TELECOMMUNICATION OPTION)  
(INSTRUMENTATION OPTION)  
MODULE I**

**ELECTRICAL MEASUREMENTS AND ANALOGUE ELECTRONICS I**

**3 hours**

**INSTRUCTIONS TO CANDIDATES**

*You should have the following for this examination:*

*Answer booklet*

*Mathematical table/Non-programmable scientific calculator;*

*Drawing instruments.*

*This paper consists of **EIGHT** questions in **TWO** sections; **A** and **B**.*

*Answer any **THREE** questions from section **A** and any **TWO** questions from section **B** in the answer booklet provided.*

*All questions carry equal marks.*

*Maximum marks for each part of a question are as indicated.*

*Candidates should answer all questions in English.*

**This paper consists of 5 printed pages.**

**Candidates should check the question paper to ascertain that  
all the pages are printed as indicated and that no questions are missing.**

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**Turn over**

## SECTION A: ELECTRICAL MEASUREMENTS

Answer any **THREE** questions from this section.

1. (a) (i) Describe the following standards with respect to measurements:
- (I) secondary;
- (II) working.
- (ii) A standard cell has a voltage rating of 1.018500 V and internal resistance of  $500\Omega$ . If the insulation resistance between its terminals is  $5\text{ M}\Omega$ , determine the:
- (I) current drain due to insulation resistance;
- (II) difference between the rated voltage and the drop due to internal resistance. (9 marks)
- (b) Derive the dimensional equation of "work done" in MLT system of units. (5 marks)
- (c) A voltmeter having a sensitivity of  $1,000\ \Omega/\text{V}$  reads 100V on its 150V scale when connected across an unknown resistor in series with a milliammeter. Neglecting the milliammeter resistance, determine the percentage error due to the loading effect of the voltmeter when the milliammeter reads 5 mA. (6 marks)
2. (a) (i) State **one** source of error in wattmeters when used in measurements.
- (ii) With the aid of a labelled block diagram, describe the heterodyne method of frequency measurement. (7 marks)
- (b) A solenoid, 1.2 m long, is uniformly wound with 800 turns. A search coil of mean diameter 30 mm, wound with 50 turns, is placed at the centre of the solenoid and connected to a ballistic galvanometer. The total resistance of the search-coil circuit is  $2000\Omega$ . When a current of 5A through the solenoid is reversed, the deflection on the galvanometer scale is 85 divisions.  
Taking  $\mu_0 = 4\pi \times 10^{-7}\text{ H/m}$ , determine the ballistic constant of the galvanometer in coulombs/unit deflection. (13 marks)

3. (a) (i) Define reliability with respect to engineering systems. (8 marks)
- (ii) Sketch, on the same axis, the curves showing the manufacturing cost against reliability and explain the shape of each curve. (8 marks)
- (b) Outline the procedure of assessing the reliability of an equipment. (8 marks)
- (c) In a test of 400 diodes, 5 failed over a 1,000 hour period. For the diodes, determine the:
- (i) failure rate; (4 marks)
- (ii) mean time to fail.
4. (a) (i) State any **two** possible causes of open circuit fault in carbon composition resistors. (7 marks)
- (ii) Figure 1 shows a schematic block diagram of a d.c motor speed control system. Explain the effect of an open circuit fault in the feedback line and how it can be verified.

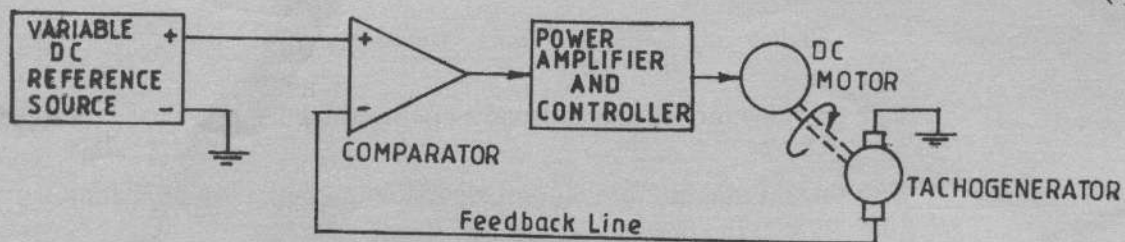


Fig. 1

- (b) With the aid of a labelled block diagram incorporating a signal generator and an oscilloscope, describe a test to determine the gain of a faulty audio amplifier. (7 marks)
- (c) In an electrical system, the probability ( $P_t$ ) of the system being returned to working condition within a time of 4 hours is 86.5%. Determine the:
- (i) mean time to repair; (6 marks)
- (ii) failure rate.

5. (a) (i) Distinguish between instrumental errors and environmental errors with respect to measurements.
- (ii) With the aid of a circuit diagram, describe how a full-wave rectifier instrument is used to measure the r.m.s value of an a.c voltage. (9 marks)
- (b) (i) With the aid of a phasor diagram, show that the power measured by the two-wattmeter method in a 3-phase system gives the total power in the system. Assume the wattmeters are connected in the red and blue phases.
- (ii) In the measurement in b(i), the readings on each wattmeter is 5.2 kW and -1.7 kW. Determine the:
- (I) total power;
- (II) power factor. (11 marks)

### SECTION B: ANALOGUE ELECTRONICS I

*Answer any TWO questions from this section.*

6. (a) (i) State any **two** merits of a full-wave centre-tapped single-phase rectifier.
- (ii) With the aid of a circuit diagram, describe the operation of a shunt capacitor filter. Sketch the output voltage waveform. (10 marks)
- (b) Show that the r.m.s. value,  $V_{r(\text{rms})}$ , of the a.c. component of the rectified voltage from a full-wave diode rectifier equals  $0.308 V_{\text{peak}}$ . (6 marks)
- (c) A series dc-to-ac inverter has an inductor of 10 mH, a capacitor of  $47 \mu\text{F}$  and a load resistor of  $5\Omega$ . Determine the:
- (i) resonant frequency;
- (ii) time period of oscillations (4 marks)

7. (a) (i) Define the following JFET parameters:  
 (I) drain-source saturation current;  
 (II) gate-source cutoff (pinch-off) voltage.
- (ii) With the aid of a labelled construction diagram, describe the operation of an n-channel depletion MOSFET and sketch its output characteristic curves. (9 marks)
- (b) Figure 2 shows a circuit diagram of a transistor amplifier. For stability reasons, the current through  $R_2$  must be ten times the base current. Taking  $\beta = 100$ ,  $V_{BE} = 0.7V$ ,  $V_C = 8V$ ,  $V_E = 2V$  and  $I_C = 1mA$ , determine the value of the bias resistors  $R_1$ ,  $R_2$ ,  $R_3$  and  $R_4$ . (11 marks)

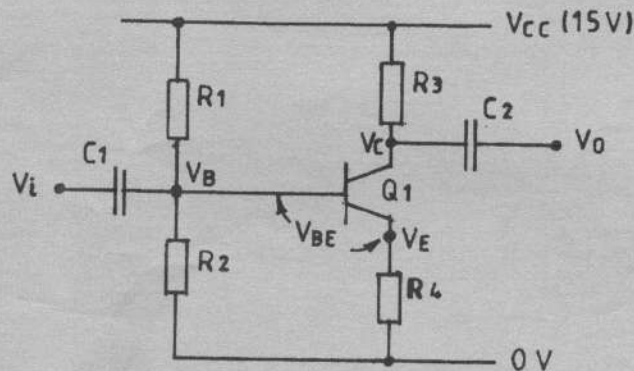


Fig. 2

8. (a) (i) State any **two** of Bohr's postulates with respect to the energy levels of an electron.
- (ii) With the aid of a covalent bond diagram of an intrinsic semiconductor, explain how a hole takes part in conduction. (8 marks)
- (b) Sketch the characteristic curve of a p-n junction diode and explain its shape. (6 marks)
- (c) An electrostatic CRO has deflection plates of length,  $l = 2$  cm and distance between them,  $d = 3$  mm. It is operated at an anode voltage,  $V_a = 2$  kV and deflection potential,  $V_d = 150$  V. Taking electron charge,  $e = 1.602 \times 10^{-19}C$  and electron mass,  $m = 9.109 \times 10^{-31}$  kg, determine the:
- (i) velocity of the electron beam;  
 (ii) transit time through the plates;  
 (iii) electric field intensity between the plates. (6 marks)

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